

Features

- · Open-loop, fluxgate-based current transducer
- 80A Single phase (40A Three phase)
- Meet IEC 62752: 2018 (IC-CPD)
- Meet IEC 62955: 2018 (RDC-PD)
- Meet the requirements of AC 30mA and DC 6mA residual current detection
- · Lead in wire, easy to use
- 5,000 A surge current capability



Ideal Power's 36TLB6-A1PCE EV Charger Residual Current Transducer Series are certified to RoHS & IEC 61010/IEC 62752 /IEC 62955 Standards and comply with the relevant Efficiency Regulations. These are primarily used in EV Automotive Industries and customised solutions are available upon request.

Models					
Model Number	Input Voltage (V DC)	Rated DC Residual Current (mA)	Rated AC Residual Current (mA)	Rated current (A)	Maximum Power Dissipation (W)
TLB6-A1PCE	5	6	30	80A/ 40A (1 phase/ 3 phase)	0.2

Electrical Characteristics					
Item	Symbol	Min	Тур	Max	Unit.
Rated Residual DC Operating Current	IΔNDC		6		mA
Rated Residual AC Operating Current	lΔNAC		30		mA
Range of Remaining DC Operating Current	^I ∆NDC-RANGE	3	4.5	6	mA
Range of Remaining AC Operating Current	l∆NAC-RANGE	15	22.5	30	mA
Input Voltage	VCC	4.85	5	5.15	V
Operating Current			30	40	mA

Protection and Detection Characteristics					
Item	Symbol	Min	Тур	Max	Unit.
Self-Check Input Low-Level Voltage	V TEST-IN IL	0		1	V
Self-Check Input High-Level Voltage	V TEST-IN IH	4		5.1	V
Calibration Input Low Voltage	V CAL-IL	0		1	V
Calibration Input High Voltage	V CAL-IH	4		5.1	V
Operating Output Low-Level Voltage	V TRIP-OL	0		0.6	V
Operating Output High-Level Voltage	V TRIP-OH	4.5		VCC	V



36TLB6-A1PCE EV Charger Residual Current Transducer

Isolation Characteristic	CS				
Item	Operating Conditions	Min	Тур	Max	Unit.
Isolation Test	Primary edge input, secondary output; 50Hz, 1min; leakage current < 1mA		4		kVAC
Insulation Resistance	1.2/50us		7		GΩ

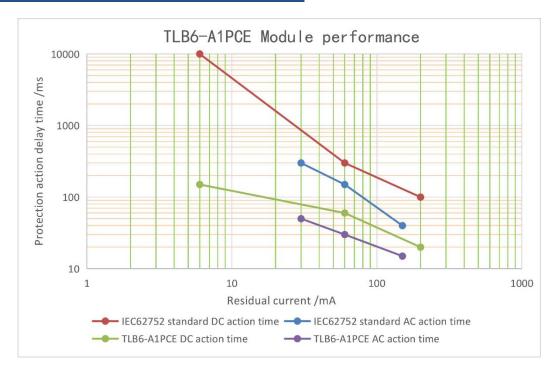
General Characteristics					
Item	Symbol	Min	Тур	Max	Unit.
Operating Temperature	Та	-40		+85	°C
Storage Temperature	Ts	-40		+125	°C
Weight	m	18	22	26	g
Vibration	20-150Hz,	2g (GB2	2423.10, IE	C60068-2-6	6)
Overvoltage Category		OVC III (IEC61010)		

Performa	nce Characteristic					
Item	Symbol	Residual Current Waveform	Min	Тур	Max	Unit.
	I∆NAC50	Frequency 50Hz AC	15	22.5	30	mA RMS
	ΙΔΝΑ0	0 Angle Pulsating DC	4.5	15	42	mA RMS
	I _Δ NA90	90 Angle Pulsating DC	6.3	15	42	mA RMS
Residual operating	I _Δ NA135	135 Angle Pulsating DC	3.3	15	42	mA RMS
current	I∆NS-DC	Smooth DC	3	4.5	6	mA RMS
	I _Δ N2PDC	Two-Phase Rectification DC	3.5	5	7	mA RMS
	I∆N3PDC	Three-Phase Rectification DC	3.1	4.5	6.2	mA RMS
	IΔNF	Composite Current	15	25	42	mA RMS
	T∆NAC50@30mA	RMS 30mA Frequency 50Hz AC		55	200	ms
	T∆NAC50@60mA	RMS 60mA Frequency 50Hz AC		30	100	ms
	T∆NAC50@150mA RMS 150mA Frequency 50Hz AC			15	20	ms
	T∆NA0@42mA	RMS 42mA 0 Angle Pulsating DC		50	200	ms
	T∆NA0@84mA RMS 84mA 0 Angle Pulsating DC			30	100	ms
	T∆NA0@210mA	RMS 210mA 0 Angle Pulsating DC		15	20	ms
	T _{∆NA0@42mA+S} - DC@6mA	RMS 42mA 0 Angle Pulsating DC with 6mA Smooth DC		38	200	ms
Response	T∆NA0@84mA+S- DC@6mA	RMS 84mA 0 Angle Pulsating DC with 6mA Smooth DC		30	100	ms
time	T∆NA0@210mA+S- DC@6mA	RMS 210mA 0 Angle Pulsating DC with 6mA Smooth DC		15	20	ms
	T∆NS-DC@6mA	6mA Smooth DC		100	200	ms
	T∆NS-DC@60mA	60mA Smooth DC	-	50		ms
	T∆NS-DC@300mA	300mA Smooth DC	-	15	20	ms
	T∆N2PDC@60mA	RMS 60mA Two Phase Rectification DC		50	100	ms
	T∆N2PDC@300mA	RMS 300mA Two Phase Rectification DC		15	20	ms
	T∆N3PDC@60mA	RMS 60mA Three Phase Rectification DC		50	100	ms
	T∆N3PDC@300mA	RMS 300mA Three Phase Rectification DC		15	20	ms
	T∆NF@210mA	RMS 210mA Composite Current		15	20	ms



	Specifications		
E	CISPR32/EN55032 CLASS B		
RE	CISPR32/EN55032 CLASS B		
SD	IEC/EN61000-4-2 Contact ±6kV, Ai	ir ±8kV	perf. Criteria A
RS	IEC/EN61000-4-3 30V/m		perf. Criteria A
FT.	IEC/EN61000-4-4 ±4kV		perf. Criteria A
Surge Current	IEC62955 6000V/2Ω/3000A, 8/20us	s	perf. Criteria B
2	E E SD S FT	E CISPR32/EN55032 CLASS B SD IEC/EN61000-4-2 Contact ±6kV, A S IEC/EN61000-4-3 30V/m FT IEC/EN61000-4-4 ±4kV	E CISPR32/EN55032 CLASS B E CISPR32/EN55032 CLASS B SD IEC/EN61000-4-2 Contact ±6kV, Air ±8kV S IEC/EN61000-4-3 30V/m FT IEC/EN61000-4-4 ±4kV

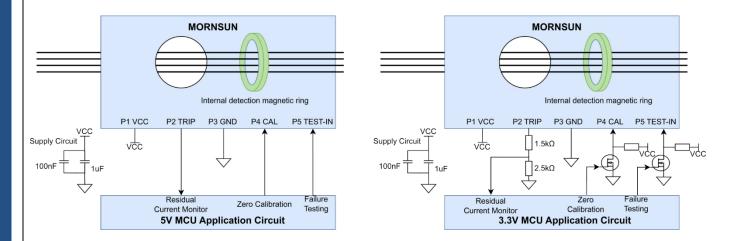
Characteristic Curve



Pin	Mark	Description
1	VCC	The product is powered by VCC, which needs to supply 5V, and 100nF and 1uF capacitors are connected in parallel at the input end.
2	TRIP	Trip output pin, when detected > 6mA DC residual current or > 30mA AC residual current, the pin is set high and a trip signal is generated.
3	GND	Product-powered ground.
4	CAL	Zero calibration pin, when the pin inputs a duration >50ms and <100ms low voltage, the calibration function is enabled and the residual current detected at the moment is used as the zero current point of the residual current compensated for subsequent detection. This residual current compensation value is stored internally and continues to be compensated upon reboot.
5	TEST- IN	Test pin, when the pin input high level, there will be a built-in residual current, making the action signal action. It can be designed for periodic self-test of products.



Connection and Description

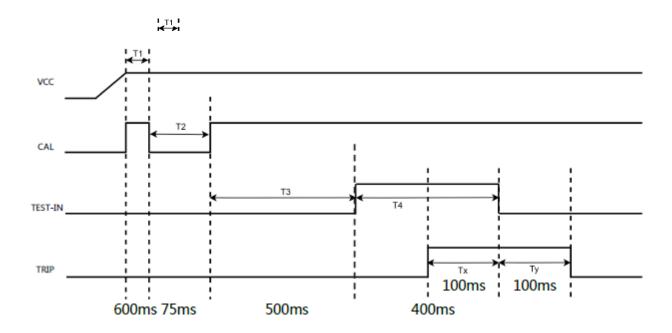


- 1. Two capacitors 1uF/16V and 100nF/16V need to be provided at VCC and GND for energy storage and decoupling.
- 2. Residual current protection monitoring pin TRIP, zero calibration pin CAL, and TEST-IN pin are generally controlled by a microcontroller.
- 3. The residual current protection detection pin will output high level when the current value flowing through the internal detection magnetic ring exceeds the specification value.
- 4. When the module is started, the zero-calibration pin should be kept at a low level for a period and then placed at a high level. See the timing sequence characteristic description.
- 5. TEST-IN is used to test the performance of residual current transducer when self-test is required, and the test signal needs to meet the timing characteristics.
- 6. Hot plug is unavailable.
- 7. The product is connected to 5V MCU for use, and it is necessary to pay attention to level matching. If a 3.3V MCU is connected, a level conversion circuit is required for voltage conversion (as shown in the figure above). The 5V voltage is converted to 3.3V by two resistors, and the ratio of the two resistors is generally selected to be close to 3:5. At the same time, the input impedance of the MCU should be considered, and the resistance value of the two voltages should not be greater than one-tenth of the input impedance of the MCU. For example, the values of the two resistors are $1.5k\Omega$ and $2.5k\Omega$ or $10k\Omega$ and $15k\Omega$. In addition, the zero-calibration function and failure testing function need to adjust the timing. For example, the zero-calibration function of the product is effective at a low level. After connecting the MOS for level conversion, the 3.3V MCU should output a high level to make the calibration function effective, and the 3.3V MCU should output a low level when the product is not calibrated. Similarly, the 3.3V MCU output low level makes the failure testing function effective. When failure testing is not in use, the 3.3V MCU should output a high level.

Timing Characteristics					
Item	Symbol	Min	Тур	Max	Unit.
Start To Calibration Interval	T1	600			
Calibrate Signal Maintenance Time	T2	50		100	
Calibration Signal Completion Wait Time	T3		500		ms
Test Signal Duration	T4	400			



Timing Application Design

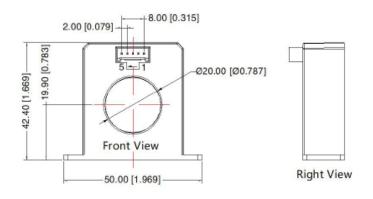


Timing application design essentials:

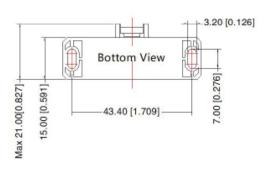
- 1. The startup speed of the VCC power supply should not be too slow, and it is recommended that the speed is greater than 10V/ms.
- 2. After the power supply is fully started, the startup and stabilisation time of the module is about 200-300ms. the zero-calibration delay time T1 should be greater than 100ms.
- 3. The zero-calibration signal duration T2 should be greater than 50ms and less than 100ms. When the CAL low time is greater than 50ms, TLB6-A1PC starts to zero calibration.
- 4. The waiting time T3 for calibration completion should be greater than 500ms.
- 5. TEST-IN self-test signal can only be enabled after T3 is completed, and the signal duration of a single round self-test must be T4 >400ms.
- 6. After delaying the delay time of the protection action, the TRIP pin outputs a high level. Generally speaking, Tx =100ms after detecting the TRIP signal, the TEST-IN can be set to a low level, and the self-test signal can be closed. Then, the high level of the TRIP pin returns to a low level after Ty=100ms.
- 7. It is recommended to use the calibration function at Ta=25°C.



Mechanical Specifications



		Pin-Out
Pin	Mark	Customer Connector
1	VCC	
2	TRIP	Housing: Yeonho SMH200-5H
3	GND	CJT A2008HB-5P
4	CAL	or equivalent
5	TEST-IN	



Note: Unit: mm[inch]

Pin diameter tolerances: $\pm 0.10[\pm 0.004]$ General tolerances: $\pm 0.50[\pm 0.02]$

Notes:

- 1. For additional information on Product Packaging, please refer to www.idealpower.co.uk. Packaging bag number: 58070020.
- 2. All index testing methods in this datasheet are based on company corporate standards.
- 3. Unless otherwise specified, parameters in this datasheet were measured under the conditions of Ta= $25\,^{\circ}$ C, humidity<75%RH with nominal input voltage.
- 4. We can provide product customisation service. Please contact our technicians directly for specific information.
- 5. This product is used in electronic equipment. Please follow the operation and instructions of the manual and use it in a standard and safe environment.
- 6. Please do not install the product in a dangerous area; beware of the risk of electric shock during operating, some modules may generate dangerous voltages (such as primary wires, power supply wires);
- 7. This product is a build-in device. After installation, the conductive part must not be touched completely. A protective box or shield can be used.
- 8. It is strictly forbidden to disassemble and assemble the products privately to prevent equipment without failure or malfunction.
- 9. Our products shall be classified according to ISO14001 and related environmental laws and regulations and shall be handled by qualified units.